

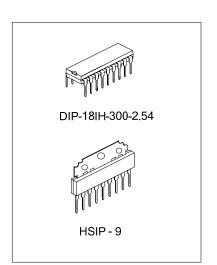
# 2×6W AUDIO POWER AMPLIFIER

## **DESCRIPTION**

SA7454 is a Class AB dual audio power amplifier. It adopts HSIP-9 or DIP-18IH-300-2.54 package.

# **FEATURES**

- \* High output power: 6 + 6W @ THD=10%, RL=4 $\Omega$ ,VCC=14.4V
- \* Fixed gain
- \* Good power supply ripple rejection
- \* Standby and Mute functions
- \* Low ON/OFF POPO noise
- \* Few external components
- \* Short circuit protection
- \* Inverting polarity protection
- \* Thermal protection



# **ORDERING INFORMATION**

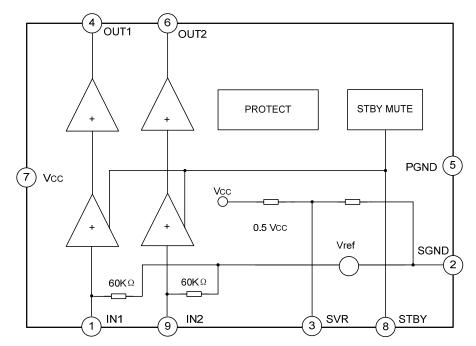
Device	Package	
SA7454	DIP-18IH-300-2.54	
SA7454H	HSIP-9	

# **APPLICATIONS**

- \* Multimedia system
- \* LCD-TV

## **BLOCK DIAGRAM**

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# **ABSOLUTE MAXIMUM RATINGS**

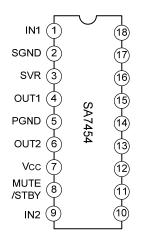
Characteristics	Symbol	Conditions	Rating	Unit	
B	Vs	Operating state	18	V	
Power Supply		No signal	20		
Max. Voltage of Inverting Polarity	Vs(r)		6	V	
Output Pin Endurance Capability	ERGo	Vs=0V	200	mJ	
Output Peak Current	Iosm	No repeat	4	Α	
	lorm	Repeat	2.5		
Total Power Dissipation	Ptot		15	W	
Storage Temperature	Tstg		-55~+150	°C	
Operating Ambient Temperature	Tamb		-40~+85	°C	
Junction Temperature	Tj		+150	°C	
Thermal Resistance from	D	SA7454H	8	°C/W	
Junction to Case	Rth(j-c)	SA7454	15		

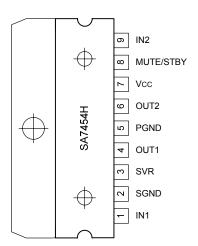
# **ELECTRICAL CHARACTERISTICS** (Unless otherwise specified, Vs=14.4V; RL=4Ω; f=1KHz; Tamb=25°C)

	Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
	Power Supply	Vs		8.5	14.4	18.0	V
	Total Quiescent Current	lq			40	80	mA
	Output DC Level	Vo			7.00		V
	0.1-15	Po	THD=0.5%	4	4.7		w
	Output Power		THD=10%	5.5	6.0		
	Total Harmonic Distortion	THD	Po=1W		0.1		%
	Low Cut-Off Frequency	flr	-3dB		45		Hz
	High Cut-Off Frequency	fhr	-1dB	20			kHz
	Closed Loop Gain	Gv		19	20	21	dB
www.DataS	heet4U.com Supply Voltage Ripple Rejection Ratio	SVRR	Operating	48			dB
			Mute	48			
			Stand-by	80			
	Input Resistance	Zi		50	60	75	kΩ
	Output Noise	Vno	Operating, Rs= $0\Omega$		50		μV
			Operating, Rs=10 $\Omega$		70	100	
			Mute		50		
	Channel Separation	CS	Rs=0Ω	40			dB
	Channel Balance	СВ			0.1	1	dB
	Thermal Protection	Тр			150		°C
	Mute Function		,				
	Mute/Play Threshold	VTMUTE		3.3		6.4	V
	Output DC Level When Mute	Vo				2	mV
	Stand-By Function		,				
	Stand-By/Mute Threshold	VTst-by		0		2.0	V
	Stand-By Quiescent Current	lq ST-BY			3.0	100	μΑ
	Stand-By Bias Current	lb ST-BY			15	40	μΑ



#### **PIN CONFIGURATION**





## **PIN DESCRIPTIONS**

Pin No.	Pin Name	I/O	Pin Description	
1	IN1		Non inverting input 1	
2	SGND	ŀ	Signal ground	
3	SVR	0	Supply voltage ripple rejection pin	
4	OUT1	0	Output 1	
5	PGND	ŀ	Power ground	
6	OUT2	0	Output 2	
7	Vcc	-	Power supply	
8	MUTE/STBY	I	Standby and mute pin	
9	IN2	I	Non inverting input 2	

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### **FUNCTION DESCRIPTION**

#### Stand-by and mute function

The MUTE/STBY controls the amplifier state by different voltages.

- When MUTE/STBY is 0 -2V, the amplifier is in standby mode, and the circuit is in power down mode;
- When MUTE/STBY is 3.3 -6.4V, the amplifier is in mute mode;
- ➤ When MUTE/STBY is higher than 8.5V, the amplifier is in operating mode.

## **Power Dissipation and Heat Sinking**

When the load is a resistor, the maximum average power that SA7454 will be required to dissipate is approximately:

PD(MAX)=
$$Vs^2/\pi^2RL+PQ$$

Where Vs is the power supply, RL is the load resistance, PQ is the quiescent power dissipation. The above equation is only an approximation which assume SA7454 an "ideal" class B output stage and power dissipation in all other parts of the circuit is constant. As an example, if the SA7454 is operated on a 14.4V power supply with a resistive load of  $4\Omega$ , it can develop up to 6W of internal power dissipation. If the die temperature is to remain below 150°C for ambient temperatures up to 50°C, the total junction-to-ambient thermal resistance must be less



than:

$$(150^{\circ}C-50^{\circ}C)/6W=16.7^{\circ}C/W$$

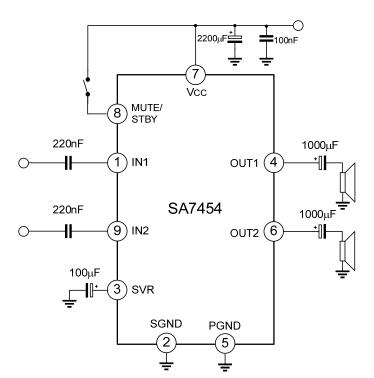
For HSIP-9 package, the die-to-package thermal resistance is  $Rth(j-c) = 8^{\circ}C/W$ , then the package-to-ambient thermal resistance should be lower than  $8.7^{\circ}C/W$ . So we need heat sink to reduce the package-to-ambient thermal resistance.

For DIP-18IH-300-2.54 package, the die-to-package thermal resistance is Rth(j-c) =  $15^{\circ}$ C/W, then the package-to-ambient thermal resistance should be lower than  $1.7^{\circ}$ C/W, that will make heat sinking difficult, in addition, DIP-18IH-300-2.54 can not add effective heat sink, so we need to reduce the power dissipation by reducing load. For example, with a  $8\Omega$  load, it can develop up to 3W of internal power dissipation, and the package-to-ambient thermal resistance should be lower than:

$$(150^{\circ}C-50^{\circ}C)/3W-15^{\circ}C/W=18.3^{\circ}C/W$$

The thermal requirements can become more difficult when SA7454 is driving a reactive load. As a general rule, the power dissipation of an amplifier driving a  $60^{\circ}$  reactive load (usually considered to be a worst-case loudspeaker load) will be roughly that of the same amplifier driving the resistive part of that load. For example, a loudspeaker may at some frequency have an impedance with a magnitude of  $8\Omega$  and a phase angle of  $60^{\circ}$ . The real part of this load will then be  $4\Omega$ , and the amplifier power dissipation equal to the power dissipation with a  $4\Omega$  load.

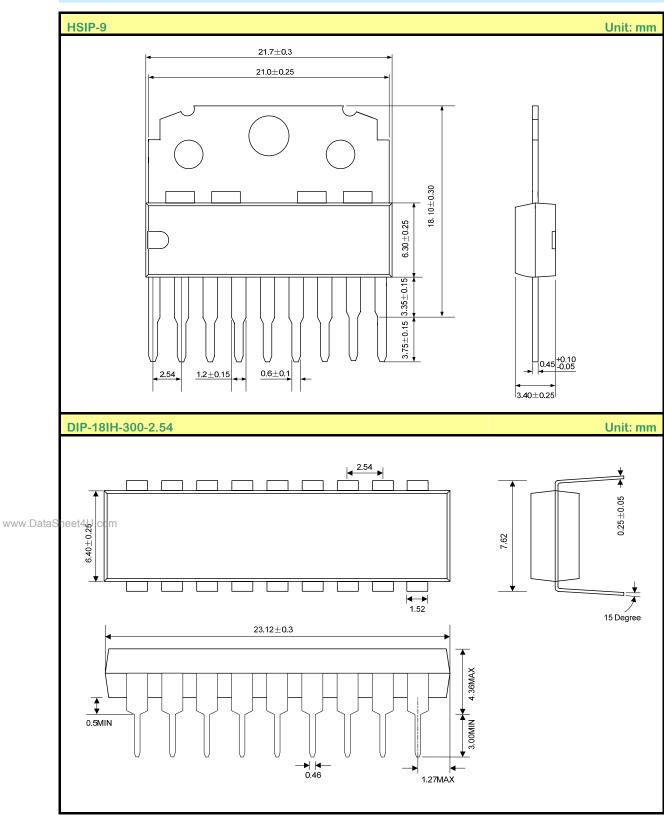
#### TYPICAL APPLICATION CIRCUIT



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# **PACKAGE OUTLINE**



Note: Silan reserves the right to make changes without notice in this specification for the improvement of the design and performance. Silan will supply the best possible product for customers.